Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1437754	LTO near silicon oxide	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 13:21
L2	41	LTO near (silicon adj oxide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 14:04
L3	1759114	treatment	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 14:04
L4	462418	plasma	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 14:04
L5	172453	L4 and 3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 14:05
L6	24255	L4 near 3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 14:05
L7	25	("5665203").URPN.	USPAT	OR	ON	2005/08/29 14:16
L8	8815	3 near 4	USPAT	OR	ON	2005/08/29 14:16
L9	8815	4 near 3	USPAT	OR	ON	2005/08/29 14:17
L10	282047	bias	USPAT	OR	ON	2005/08/29 14:20
L11	289707	9 nead 10	USPAT	OR	ON	2005/08/29 14:17
L12	2991911	zero or no	USPAT	OR	ON	2005/08/29 14:17
L13	2	9 near 10	USPAT	OR	ON	2005/08/29 15:33
L14	125166	RF	USPAT	OR	ON	2005/08/29 14:20
L15	62	9 near 14	USPAT	OR	ON	2005/08/29 14:22
L16	8432	plasma near etch	USPAT	OR	ON	2005/08/29 14:22
L17	3	15 and 16	USPAT	OR	ON	2005/08/29 14:23
L18	3669	reduce near (charge or charging)	USPAT	OR	ON	2005/08/29 14:23
L19	571	18 and 4	USPAT	OR	ON	2005/08/29 14:23
L20	222	19 and 10	USPAT	OR	ON	2005/08/29 14:24

L21	106	20 and 14	USPAT	OR	ON	2005/08/29 14:24
L22	547792	inert or ambient	USPAT	OR	ON	2005/08/29 14:24
L23	58	21 and 22	USPAT	OR	ON	2005/08/29 14:29
L24	12	23 and 16	USPAT	OR	ON	2005/08/29 14:29
L25	20853	PMOS	USPAT	OR	ON	2005/08/29 15:33
L26	0	"6656832.pn"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 15:58
L27	2	"6656832".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 15:59
L28	436442	high adj frequency	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 16:00
L29	211441	MHz	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 16:00
L30	689	28 near 28	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 16:00
L31	11	zero near (RF adj bias)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 16:15
L32	0	31 and 30	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 16:00
L33	1	09/775664	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 16:08
L34	8	inductively adj coupled near plasma near etch.ab.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 16:16

L35	0	inductively adj coupled near etch.ab.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 16:17
L36	866	inductively adj coupled and etch.ab.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 16:17
L37	328	36 and RIE	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 16:17
L38	208	37 and bias	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 16:17
L39	172	38 and RF	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 16:17
L40	107	39 and MHZ	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 16:29
L42	2305	(no or zero) near bis	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 16:29
L43	0	40 and 42	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 16:30
L44	2641	overetch	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 16:30
L45	3993	no near bias	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 16:30

L46	35	44 and 45	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 16:40
S1	462418	plasma	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 10:47
S2	199877	etch	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 10:47
S3	17184	S1 near S2	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 10:48
S4	60405	Chang.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 10:49
S5	374	S3 and S4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 10:48
S8	29319	Chang adj et	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 10:49
S9	1293	S4 and S8	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 10:49
S10	22	S3 and S9	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 10:50
S11	1026571	silicon nitride	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 10:50

S12	21	S10 and S11	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 11:04
S13	2	"5,665,203".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/29 15:57